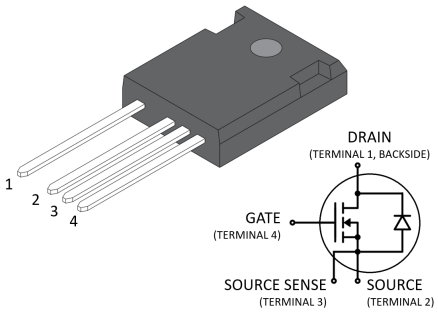
# MSC035SMA170B4 Silicon Carbide N-Channel Power MOSFET

## Product Overview

The silicon carbide (SiC) power MOSFET product line from Microsemi increases the performance over silicon MOSFET and silicon IGBT solutions while lowering the total cost of ownership for high-voltage applications. The MSC035SMA170B4 device is a 1700 V, 35 mΩ SiC MOSFET in a TO-247 4-lead package with a source sense.




### Features

The following are key features of the MSC035SMA170B4 device:

- Low capacitances and low gate charge
- Fast switching speed due to low internal gate resistance (ESR)
- Stable operation at high junction temperature, $T_{J(max)}$ = 175 °C
- Fast and reliable body diode
- Superior avalanche ruggedness
- RoHS compliant

### Benefits

The following are benefits of the MSC035SMA170B4 device:

- High efficiency to enable lighter, more compact system
- Simple to drive and easy to parallel
- Improved thermal capabilities and lower switching losses
- Eliminates the need for external freewheeling diode
- Lower system cost of ownership

### Applications

The MSC035SMA170B4 device is designed for the following applications:

- PV inverter, converter, and industrial motor drives
- Smart grid transmission and distribution
- Induction heating and welding
- H/EV powertrain and EV charger
- Power supply and distribution

# Device Specifications

This section shows the specifications of the MSC035SMA170B4 device.

## Absolute Maximum Ratings

The following table shows the absolute maximum ratings of the MSC035SMA170B4 device.

**Table 1 • Absolute Maximum Ratings**

| Symbol | Characteristic | Ratings | Unit |
|---|---|---|---|
| $V_{DSS}$ | Drain source voltage | 1700 | V |
| $I_D$ | Continuous drain current at $T_C$ = 25 °C | 68 | A |
| | Continuous drain current at $T_C$ = 100 °C | 48 | |
| $I_{DM}$ | Pulsed drain current [1] | 200 | |
| $V_{GS}$ | Gate-source voltage | 23 to –10 | V |
| $P_D$ | Total power dissipation at $T_C$ = 25 °C | 370 | W |
| | Linear derating factor | 2.47 | W/°C |

**Note:**

**1.** Repetitive rating: pulse width and case temperature limited by maximum junction temperature.

The following table shows the thermal and mechanical characteristics of the MSC035SMA170B4 device.

**Table 2 • Thermal and Mechanical Characteristics**

| Symbol | Characteristic | Min | Typ | Max | Unit |
|---|---|---|---|---|---|
| $R_{\theta JC}$ | Junction-to-case thermal resistance | | 0.27 | 0.41 | °C/W |
| $T_J$ | Operating junction temperature | –55 | | 175 | °C |
| $T_{STG}$ | Storage temperature | –55 | | 150 | |
| $T_L$ | Soldering temperature for 10 seconds (1.6 mm from case) | | | 260 | |
| | Mounting torque, 6-32 or M3 screw | | | 10 | lbf-in |
| | | | | 1.1 | N-m |
| Wt | Package weight | | 0.22 | | oz |
| | | | 6.2 | | g |

## Electrical Performance

The following table shows the static characteristics of the MSC035SMA170B4 device. $T_J$ = 25 °C unless otherwise specified.

**Table 3 • Static Characteristics**

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $V_{(BR)\ DSS}$ | Drain-source breakdown voltage | $V_{GS}$ = 0 V, $I_D$ = 100 µA | 1700 | | | V |
| $R_{DS(on)}$ | Drain-source on resistance [1] | $V_{GS}$ = 20 V, $I_D$ = 30 A | | 35 | 45 | mΩ |
| $V_{GS(th)}$ | Gate-source threshold voltage | $V_{GS}$ = $V_{DS}$, $I_D$ = 2.5 mA | 1.8 | 3.25 | | V |
| $\Delta V_{GS(th)}/\Delta T_J$ | Threshold voltage coefficient | $V_{GS}$ = $V_{DS}$, $I_D$ = 2.5 mA | | –5.1 | | mV/°C |
| $I_{DSS}$ | Zero gate voltage drain current | $V_{DS}$ = 1700 V, $V_{GS}$ = 0 V | | | 100 | µA |
| | | $V_{DS}$ = 1700 V, $V_{GS}$ = 0 V<br>$T_J$ = 125 °C | | | 500 | |
| $I_{GSS}$ | Gate-source leakage current | $V_{GS}$ = 20 V/–10 V | | | ±100 | nA |

**Note:**

**1.** Pulse test: pulse width < 380 µs, duty cycle < 2%.

The following table shows the dynamic characteristics of the MSC035SMA170B4 device. $T_J$ = 25 °C unless otherwise specified.

**Table 4 • Dynamic Characteristics**

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $C_{iss}$ | Input capacitance | $V_{GS}$ = 0 V, $V_{DD}$ = 1000 V<br>$V_{AC}$ = 25 mV, ƒ = 1 MHz | | 3300 | | pF |
| $C_{rss}$ | Reverse transfer capacitance | | | 10 | | |
| $C_{oss}$ | Output capacitance | | | 150 | | |
| $Q_g$ | Total gate charge | $V_{GS}$ = –5 V/20 V, $V_{DD}$ = 850 V<br>$I_D$ = 30 A | | 178 | | nC |
| $Q_{gs}$ | Gate-source charge | | | 49 | | |
| $Q_{gd}$ | Gate-drain charge | | | 27 | | |
| $t_{d(on)}$ | Turn-on delay time | $V_{DD}$ = 1300 V, $V_{GS}$ = –5 V/20 V<br>$I_D$ = 50 A $R_{G(ext)}$ = 4 Ω[1],<br>Freewheeling diode =<br>MSC035SMA170B4 (Vg = –5 V) | | 7 | | ns |
| $t_r$ | Current rise time | | | 7 | | |
| $t_{d(off)}$ | Turn-off delay time | | | 15 | | |

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $t_f$ | Current fall time | | | 17 | | |
| $E_{on}$ | Turn-on switching energy [2] | | | 1372 | | µJ |
| $E_{off}$ | Turn-off switching energy | | | 265 | | |
| $t_{d(on)}$ | Turn-on delay time | $V_{DD}$ = 1300 V, $V_{GS}$ = –5 V/20 V<br>$I_D$ = 50 A $R_{G(ext)}$ = 4 Ω[1],<br>Freewheeling diode = MSC050SDA170B | | 7 | | ns |
| $t_r$ | Current rise time | | | 7 | | |
| $t_{d(off)}$ | Turn-off delay time | | | 15 | | |
| $t_f$ | Current fall time | | | 17 | | |
| $E_{on}$ | Turn-on switching energy [2] | | | 1363 | | µJ |
| $E_{off}$ | Turn-off switching energy | | | 244 | | |
| ESR | Equivalent series resistance | f = 1 MHz, 25 mV, drain short | | 0.85 | | Ω |
| SCWT | Short circuit withstand time | $V_{DS}$ = 1200 V, $V_{GS}$ = 20 V | | 3 | | µs |
| $E_{AS}$ | Avalanche energy, single pulse | $V_{DS}$ = 150 V, $V_{GS}$ = 20 V, $I_D$ = 30 A | | 4000 | | mJ |

**Notes:**

1. $R_G$ is total gate resistance excluding internal gate driver impedance.
2. $E_{on}$ includes energy of the freewheeling diode.

The following table shows the body diode characteristics of the MSC035SMA170B4 device. $T_J$ = 25 °C unless otherwise specified.

**Table 5 • Body Diode Characteristics**

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $V_{SD}$ | Diode forward voltage | $I_{SD}$ = 30 A, $V_{GS}$ = 0 V | | 3.7 | | V |
| | | $I_{SD}$ = 30 A, $V_{GS}$ = –5 V | | 3.9 | | V |
| $t_{rr}$ | Reverse recovery time | $I_{SD}$ = 50 A, $V_{GS}$ = –5 V<br>$V_{DD}$ = 1200 V dI/dt = –8000 A/µs | | 27 | | ns |
| $Q_{rr}$ | Reverse recovery charge | | | 650 | | nC |
| $I_{RRM}$ | Reverse recovery current | | | 46 | | A |

## Typical Performance Curves

This section shows the typical performance curves of the MSC035SMA170B4 device.

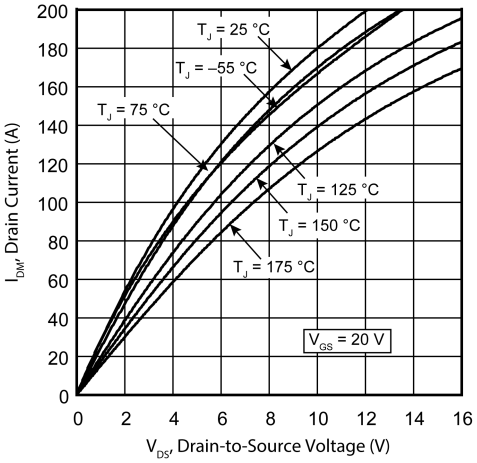



**Figure 1 • Drain Current vs. $V_{DS}$**

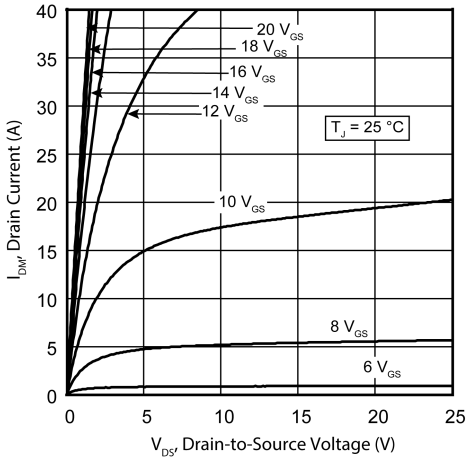



**Figure 2 • Drain Current vs. $V_{DS}$**

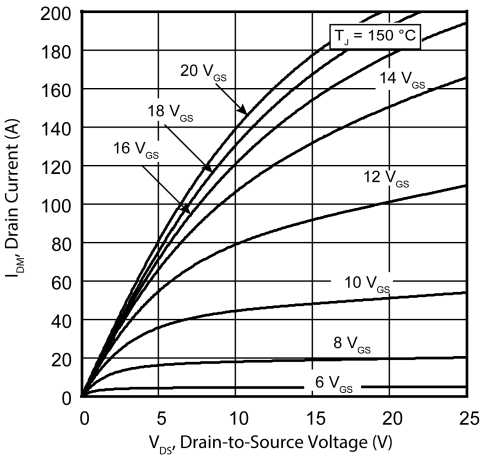



**Figure 3 • Drain Current vs. $V_{DS}$**

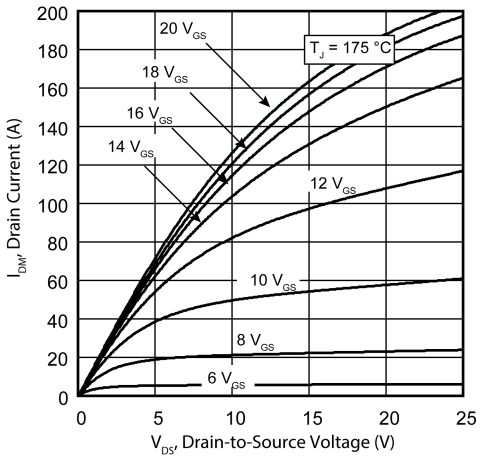



**Figure 4 • Drain Current vs. $V_{DS}$**

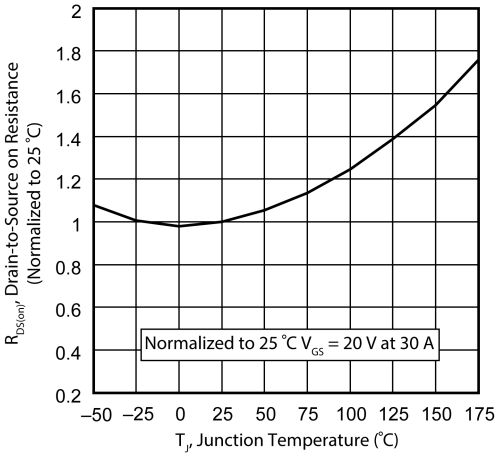



**Figure 5 • RDS(on) vs. Junction Temperature**

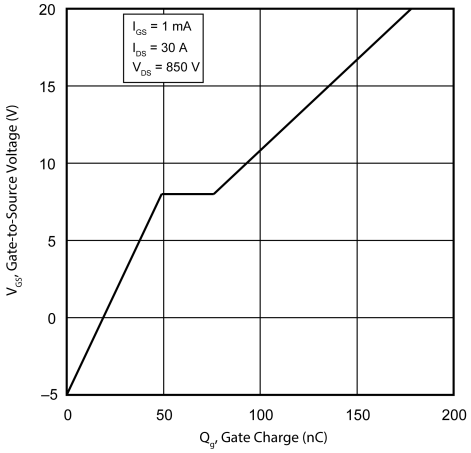



**Figure 6 • Gate Charge Characteristics**

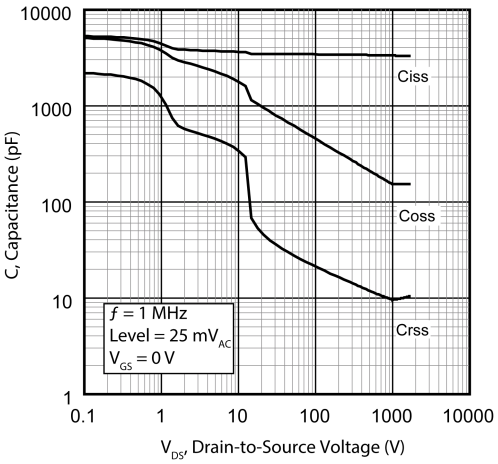



**Figure 7 • Capacitance vs. Drain-to-Source Voltage**

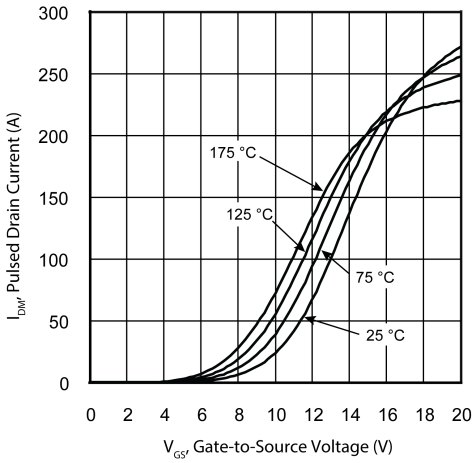



**Figure 8 • IDM vs. Gate-to-Source Voltage**

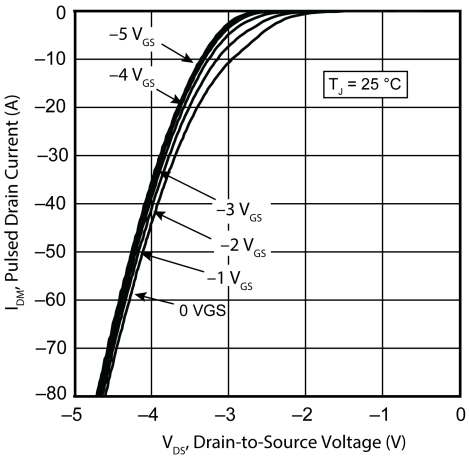



**Figure 9 • $I_{DM}$ vs. $V_{DS}$ 3rd Quadrant Conduction**

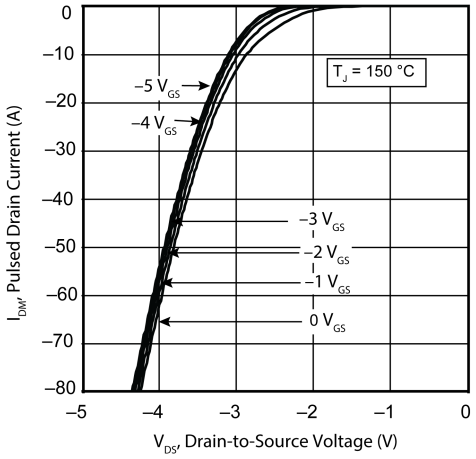



**Figure 10 • $I_{DM}$ vs. $V_{DS}$ 3rd Quadrant Conduction**

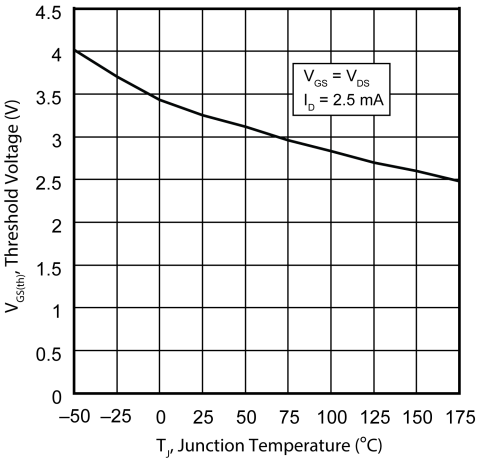



**Figure 11 • Threshold Voltage vs. Junction Temp.**

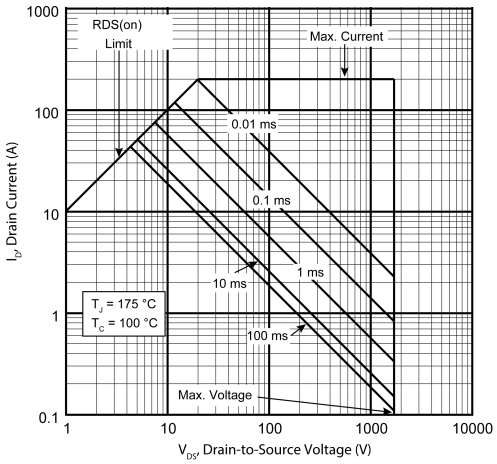



**Figure 12 • Forward Safe Operating Area**

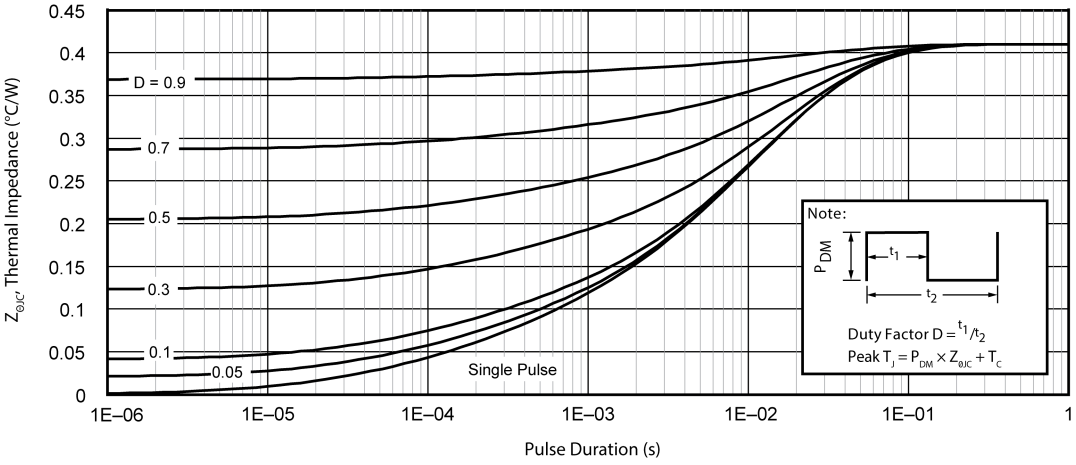



**Figure 13 • Maximum Transient Thermal Impedance**

# Package Specification

This section shows the package specification of the MSC035SMA170B4 device.

## Package Outline Drawing

The following figure illustrates the TO-247 4 lead package drawing for the MSC035SMA170B4 device. The dimensions in the figure below are in millimeters and (inches).

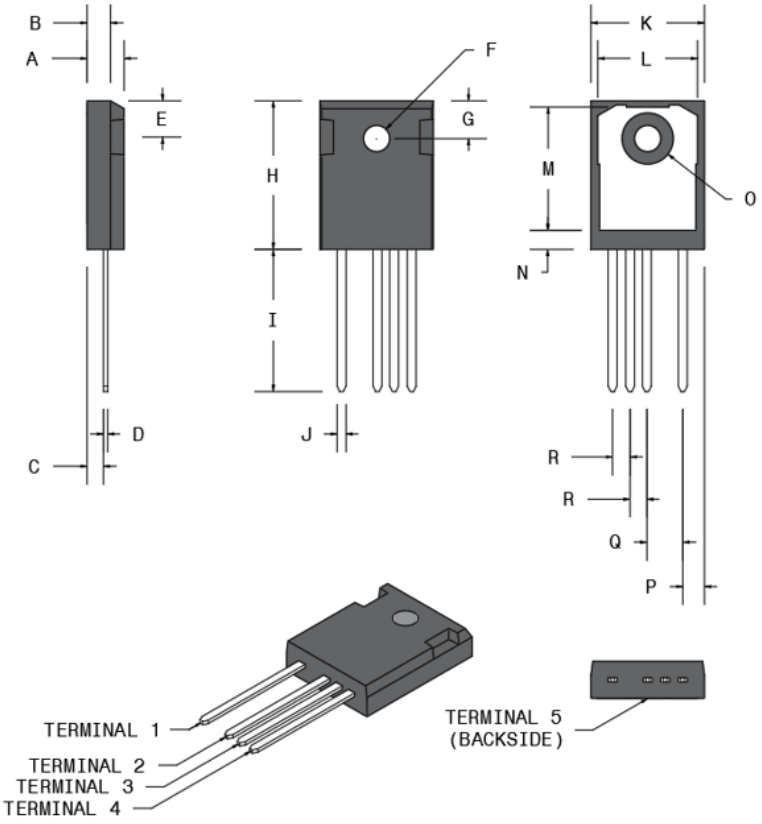



**Figure 14 • Package Outline Drawing**

The following table shows the TO-247 4-lead dimensions and should be used in conjunction with the package outline drawing.

**Table 6 • TO-247-4L Dimensions**

| Symbol | Min (mm) | Max (mm) | Min (in.) | Max (in.) |
|---|---|---|---|---|
| A | 4.90 | 5.17 | 0.193 | 0.204 |
| B | 1.85 | 2.11 | 0.073 | 0.083 |
| C | 2.25 | 2.51 | 0.089 | 0.099 |
| D | 0.55 | 0.68 | 0.022 | 0.027 |
| E | 5.49 | 5.74 | 0.216 | 0.226 |

| Symbol | Min (mm) | Max (mm) | Min (in.) | Max (in.) |
|---|---|---|---|---|
| F | 3.56 | 3.66 | 0.140 | 0.144 |
| G | 6.15 BSC | | 0.242 BSC | |
| H | 20.83 | 21.08 | 0.820 | 0.830 |
| I | 19.81 | 20.32 | 0.780 | 0.800 |
| J | 1.07 | 1.33 | 0.042 | 0.052 |
| K | 15.77 | 16.03 | 0.621 | 0.631 |
| L | 13.89 | 14.15 | 0.547 | 0.557 |
| M | 16.25 | 16.85 | 0.640 | 0.663 |
| N | 2.00 | 2.75 | 0.079 | 0.108 |
| O | 7.10 | 7.50 | 0.280 | 0.295 |
| P | 2.87 BSC | | 0.113 BSC | |
| Q | 5.08 BSC | | 0.200 BSC | |
| R | 2.54 BSC | | 0.100 BSC | |
| Terminal 1 | Drain | | | |
| Terminal 2 | Source | | | |
| Terminal 3 | Source sense | | | |
| Terminal 4 | Gate | | | |
| Terminal 5 | Drain | | | |

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